

STPSC606

600 V power Schottky silicon carbide diode

Features

- No or negligible reverse recovery
- Switching behavior independent of temperature
- Dedicated to PFC boost diode

Description

The SiC diode is an ultrahigh performance power Schottky diode. It is manufactured using a silicon carbide substrate. The wide bandgap material allows the design of a Schottky diode structure with a 600 V rating. Due to the Schottky construction no recovery is shown at turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature.

ST SiC diodes will boost the performance of PFC operations in hard switching conditions.

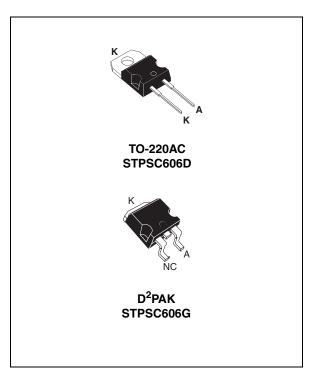


Table 1. Device summary

I _{F(AV)}	6 A
V _{RRM}	600 V
T _{j (max)}	175 °C
Q _{C (typ)}	6 nC

Characteristics STPSC606

1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C unless otherwise specified)

Symbol	Para	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage		600	V
I _{F(RMS)}	Forward rms current		18	Α
I _{F(AV)}	Average forward current $T_c = 125 ^{\circ}\text{C}, \delta = 0.5$		6	Α
	Curae non repetitive femuera	$t_p = 10 \text{ ms sinusoidal}, T_c = 25 ^{\circ}\text{C}$		
I _{FSM}	Surge non repetitive forward current	$t_p = 10 \text{ ms sinusoidal, } T_c = 125 ^{\circ}\text{C}$	22	Α
	Carrent	$t_p = 10 \mu s \text{ square}, T_c = 25 °C$	110	
I _{FRM}	Repetitive peak forward current $\delta = 0.1$, $T_c = 110$ °C, $T_j = 150$ °C		27	Α
T _{stg}	Storage temperature range		-55 to +175	°C
T _j	Operating junction temperature range		-40 to +175	°C

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit	
R _{th(j-c)}	Junction to case	2.8	°C/W	

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage	T _j = 25 °C	V- - V	-	15	75	μA
^{'R} Current	T _j = 150 °C	$V_R = V_{RRM}$	-	100	750	μΛ	
V _E ⁽²⁾	Forward voltage drop	T _j = 25 °C	-	1.4	1.7	V	
VF Y FOIM	Torward voilage drop	T _j = 150 °C	IF-UA	-	1.6	2.1	V

^{1.} $t_p = 10 \text{ ms}, \delta < 2\%$

To evaluate the conduction losses use the following equation:

 $P = 1.20x I_{F(AV)} + 0.15 x I_{F^{2}(RMS)}$

Table 5. Other parameters

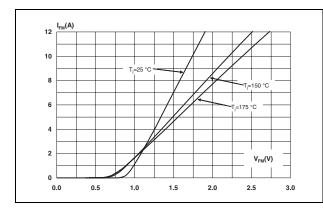
Symbol	Parameter	Test conditions	Тур.	Unit
Q _c	Total capacitive charge	$V_r = 400 \text{ V}, I_F = 6 \text{ A } dI_F/dt = -200 \text{ A/}\mu\text{s}$ $T_j = 150 \text{ °C}$	6	nC
С	Total capacitance	$V_r = 0 \text{ V}, T_c = 25 \text{ °C}, F = 1 \text{ Mhz}$	375	pF
	Total capacitatice	$V_r = 400 \text{ V}, T_c = 25 ^{\circ}\text{C}, F = 1 \text{ Mhz}$	30	РΙ

^{2.} $t_p = 500 \ \mu s, \ \delta < 2\%$

STPSC606 Characteristics

Figure 1. Forward voltage drop versus forward current (typical values)

Figure 2. Reverse leakage current versus reverse voltage applied (maximum values)



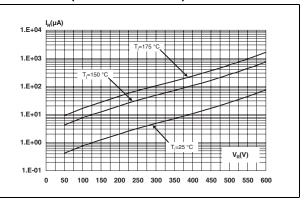
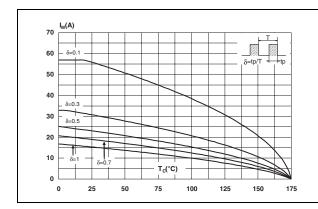
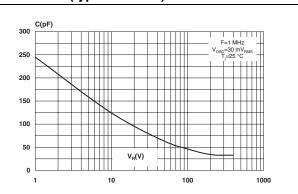


Figure 3. Peak forward current versus case temperature

Figure 4. Junction capacitance versus reverse voltage applied (typical values)

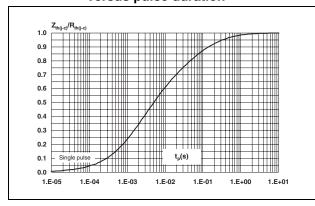




Characteristics STPSC606

Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

Figure 6. Non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)



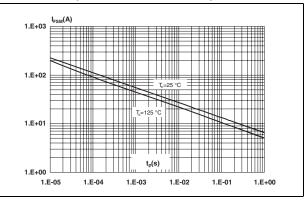
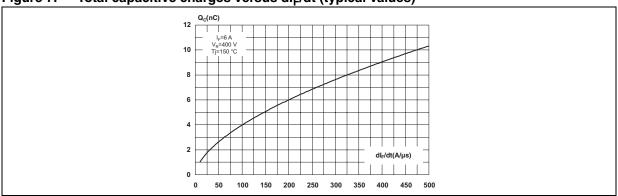


Figure 7. Total capacitive charges versus dl_F/dt (typical values)



4/8 Doc ID 16284 Rev 1

2 Package information

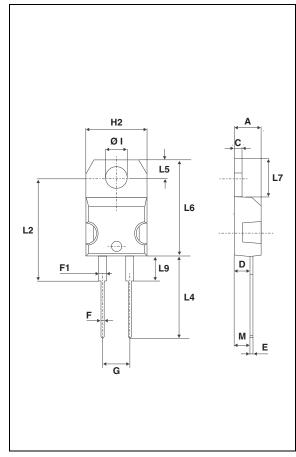
Epoxy meets UL94, V0

• Cooling method: convection (C)

Recommended torque: 0.4 to 0.6 N⋅m

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Table 6. TO-220AC dimensions



	Dimensions			
Ref.	Millimeters		Inc	hes
	Min.	Max.	Min.	Max.
Α	4.40	4.60	0.173	0.181
С	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
Е	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044 0.060	
G	4.95	5.15	0.194 0.202	
H2	10.00	10.40	0.393	0.409
L2	16.40	O typ.	0.645 typ.	
L4	13.00	14.00	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600 0.620	
L7	6.20	6.60	0.244 0.259	
L9	3.50	3.93	0.137 0.154	
М	2.6 typ.		0.102	2 typ.
Diam. I	3.75	3.85	0.147 0.151	

Package information STPSC606

Max.

0.181

0.106

0.009

0.037

0.067

0.024

0.054

0.368

0.409

0.208

0.624

0.055

0.069

0.126

Table 7. D²PAK dimensions

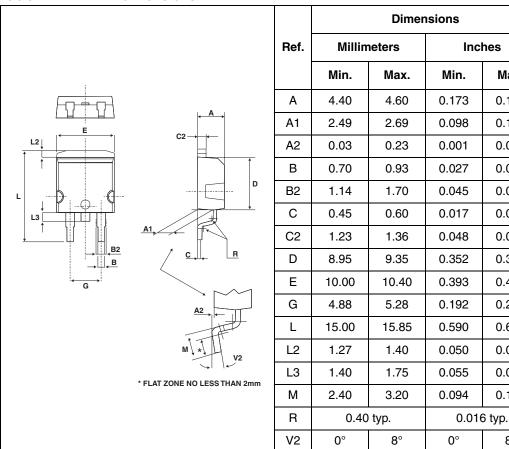
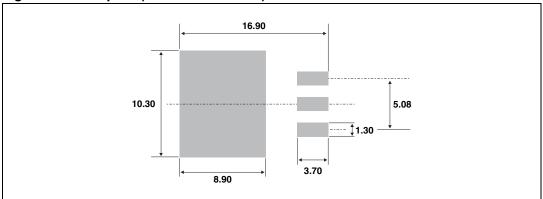


Figure 8. Footprint (dimensions in mm)



6/8 Doc ID 16284 Rev 1

3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPSC606D	STPSC606D	TO-220AC	1.86 g	50	Tube
STPSC606G-TR	STPSC606G	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

Table 9. Document revision history

Date	Revision	Changes
24-Sep-2009	1	First issue.

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8/8 Doc ID 16284 Rev 1

